SCLS331F - MARCH 1996 - REVISED JANUARY 2000

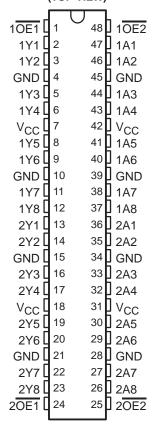
- Members of the Texas Instruments Widebus™ Family
- EPIC[™] (Enhanced-Performance Implanted CMOS) Process
- Operating Range 2-V to 5.5-V V_{CC}
- Distributed V_{CC} and GND Pins Minimize High-Speed Switching Noise
- Flow-Through Architecture Optimizes PCB Layout
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015
- Package Options Include Plastic Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), and Thin Very Small-Outline (DGV) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings

description

These 16-bit buffers and bus drivers provide a high-performance bus interface for wide data paths.

The 3-state control gate is a 2-input AND gate with active-low inputs so that if either output-enable (OE1 or OE2) input is high, all corresponding outputs are in the high-impedance state.

SN54AHC16540 . . . WD PACKAGE SN74AHC16540 . . . DGG, DGV, OR DL PACKAGE (TOP VIEW)



To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHC16540 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AHC16540 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE (each 8-bit buffer/driver)

	INPUTS									
OE1	OE2	Α	Y							
L	L	L	Н							
L	L	Н	L							
Н	X	Χ	Z							
Х	Н	Χ	Z							

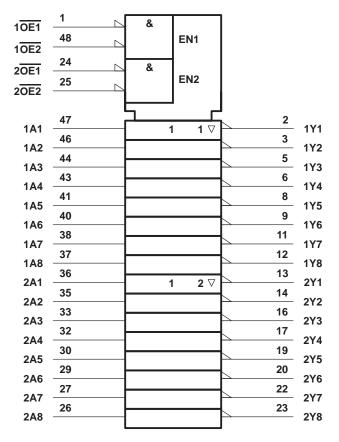


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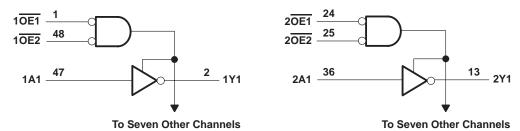


logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	–0.5 V to 7 V
Output voltage range, VO (see Note 1)	0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$)	–20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	±25 mA
Continuous current through each V _{CC} or GND	±75 mA
Package thermal impedance, θ_{JA} (see Note 2): DGG package	70°C/W
DGV package	58°C/W
DL package	63°C/W
Storage temperature range, T _{stq}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 3)

			SN54AH0	C16540	SN74AH0	C16540	UNIT	
			MIN	MAX	MIN	MAX	UNII	
Vcc	Supply voltage		2	5.5	2	5.5	V	
		V _{CC} = 2 V	1.5		1.5			
VIH	High-level input voltage	V _{CC} = 3 V	2.1		2.1		V	
		V _{CC} = 5.5 V	3.85		3.85		1	
		V _{CC} = 2 V		0.5		0.5		
VIL	Low-level input voltage	V _{CC} = 3 V		0.9		0.9	V	
		V _{CC} = 5.5 V		1.65		1.65	1	
٧ı	Input voltage	•	0.0	5.5	0	5.5	V	
٧o	Output voltage		.0	Vcc	0	Vcc	V	
		V _{CC} = 2 V	20	-50		-50	μΑ	
IОН	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	80	-4		-4	mA	
		$V_{CC} = 5 V \pm 0.5 V$	4	-8		-8	mA	
		V _{CC} = 2 V		50		50	μΑ	
lOL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4		4	A	
		$V_{CC} = 5 V \pm 0.5 V$		8		8	mA	
44/4		$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100		100	//	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 5 V \pm 0.5 V$		20		20	ns/V	
T _A	Operating free-air temperature	•	-55	125	-40	85	°C	

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51.

SN54AHC16540, SN74AHC16540 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	Vaa	T,	Δ = 25°C	;	SN54AHC	16540	SN74AHC	16540	UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
		2 V	1.9	2		1.9		1.9		
	I _{OH} = -50 μA	3 V	2.9	3		2.9		2.9		
Voн		4.5 V	4.4	4.5		4.4		4.4		V
	I _{OH} = -4 mA	3 V	2.58			2.48		2.48		
	I _{OH} = -8 mA	4.5 V	3.94			3.8	4	3.8		
		2 V			0.1		0.1		0.1	
	I _{OL} = 50 μA	3 V			0.1		0.1		0.1	
V _{OL}		4.5 V			0.1	7	0.1		0.1	V
	I _{OL} = 4 mA	3 V			0.36	35	0.5		0.44	
	I _{OL} = 8 mA	4.5 V			0.36	90	0.5		0.44	
lį	$V_I = V_{CC}$ or GND	0 V to 5.5 V			±0.1	No.	±1*		±1	μΑ
loz	$V_O = V_{CC}$ or GND, $V_I (\overline{OE}) = V_{IL}$ or V_{IH}	5.5 V			±0.25		±2.5		±2.5	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ
C _i	V _I = V _{CC} or GND	5 V		2	10				10	pF
Co	$V_O = V_{CC}$ or GND	5 V		3						pF

 $^{^{\}star}$ On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	Δ = 25°(C	SN54AH	C16540	SN74AH0	16540	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	Α	Y	C _I = 15 pF		4.8**	8.4**	1**	10**	1	10	ns
t _{PHL}	Α	'	C[= 13 pi		4.8**	8.4**	1**	10**	1	10	115
^t PZH	ŌĒ	Y	C 15 pE		6.8**	10.6**	1**	12.5**	1	12.5	ns
t _{PZL}	OE	1	C _L = 15 pF		6.8**	10.6**	1**	12.5**	1	12.5	115
t _{PHZ}	ŌĒ	Y	C: 45 pF		6.8**	11.5**	1**	12.5**	1	12.5	20
tPLZ	OE	1	C _L = 15 pF		6.8**	11.5**	1**	12.5**	1	12.5	ns
t _{PLH}	А	Y	C: 50 pF		7.7	11	1	12.5	1	12.5	20
tPHL	А	Ť	C _L = 50 pF		7.3	11	251	12.5	1	12.5	ns
^t PZH	ŌĒ	Y	C _I = 50 pF		9.7	14.1	O 1	16	1	16	ns
t _{PZL}	OE	1	CL = 50 pr		7.1	14.1	Q 1	16	1	16	115
t _{PHZ}	ŌĒ	Y	C: 50 pF		9.4	14	1	16	1	16	20
tPLZ	OE	ľ	C _L = 50 pF		9.7	14	1	16	1	16	ns
^t sk(o)			C _L = 50 pF			1.5***				1.5	ns

^{**} On products compliant to MIL-PRF-38535, this parameter is not production tested.



^{***} On products compliant to MIL-PRF-38535, this parameter does not apply.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	TA	√ = 25°C	;	SN54AH0	C16540	SN74AH0	16540	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
t _{PLH}	Α	Y	C _I = 15 pF		3.7*	6*	1*	7*	1	7	ns
t _{PHL}	ζ.	'	CL = 13 pr		3.7*	6*	1*	7*	1	7	115
^t PZH	ŌĒ	Y	C _I = 15 pF		4.7*	7.3*	1*	8.5*	1	8.5	ns
tPZL	OE	'	GL = 13 pr		4.7*	7.3*	1*	8.5*	1	8.5	115
^t PHZ	ŌĒ	Y	C _L = 15 pF		4.5*	7.2*	1*	8.5*	1	8.5	ns
t _{PLZ}	OE	'	OL = 13 pi	4.5* 7.2* 1* 8.5*	8.5*	1	8.5	113			
tPLH	Α	Y	C ₁ = 50 pF		5.2	8	1	9	1	8.5	ns
t _{PHL}	ζ	'	OL = 00 Pi		5.2	8	25	9	1	8.5	115
^t PZH	ŌĒ	Y	C _I = 50 pF		6.2	9.3	0 1	10.5	1	10.5	ns
tPZL	OE	'	CL = 30 pr		6.2	9.3	2 1	10.5	1	10.5	115
^t PHZ	ŌE	Y	C _I = 50 pF		6	9.2	1	10.5	1	10.5	ns
t _{PLZ}	OE	!	OL = 30 bi		6	9.2	1	10.5	1	10.5	115
tsk(o)		·	C _L = 50 pF			1**				1	ns

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, $V_{CC} = 5 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 4)

	PARAMETER	SN74	SN74AHC16540				
	FARAWETER	MIN	MIN TYP MAX				
V _{OL(P)}	Quiet output, maximum dynamic VOL		0.6		V		
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.3		V		
V _{OH(V)}	Quiet output, minimum dynamic VOH		4.7		V		
VIH(D)	High-level dynamic input voltage	3.5			V		
V _{IL(D)}	Low-level dynamic input voltage			1.5	V		

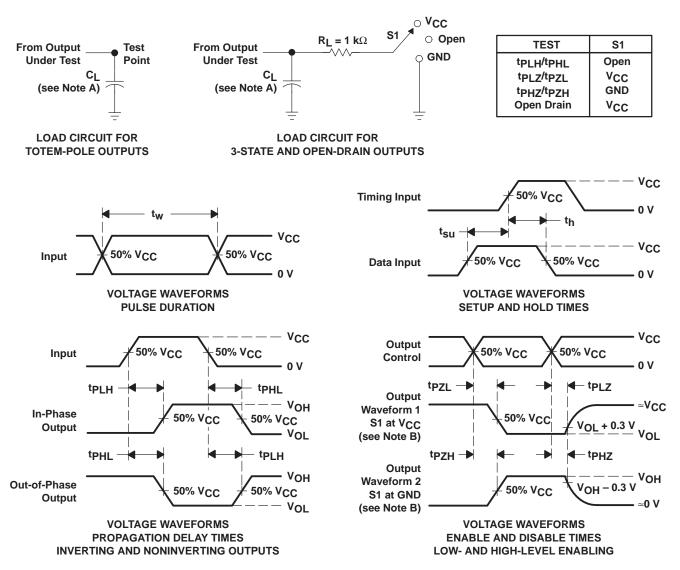
NOTE 4: Characteristics are for surface-mount packages only.

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd} Power dissipation capacitance	No load, f = 1 MHz	13	pF

^{**} On products compliant to MIL-PRF-38535, this parameter does not apply.

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \ \Omega$, $t_f \leq 3 \ ns$, $t_f \leq 3 \ ns$.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

www.ti.com

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AHC16540DGGR	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC16540	Samples
SN74AHC16540DL	ACTIVE	SSOP	DL	48	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC16540	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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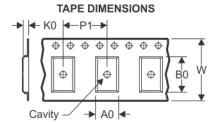
10-Dec-2020

PACKAGE MATERIALS INFORMATION

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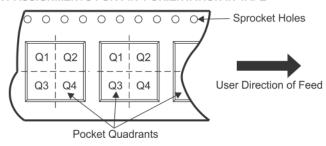
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC16540DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1

www.ti.com 5-Jan-2022



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74AHC16540DGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0	

PACKAGE MATERIALS INFORMATION

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TUBE

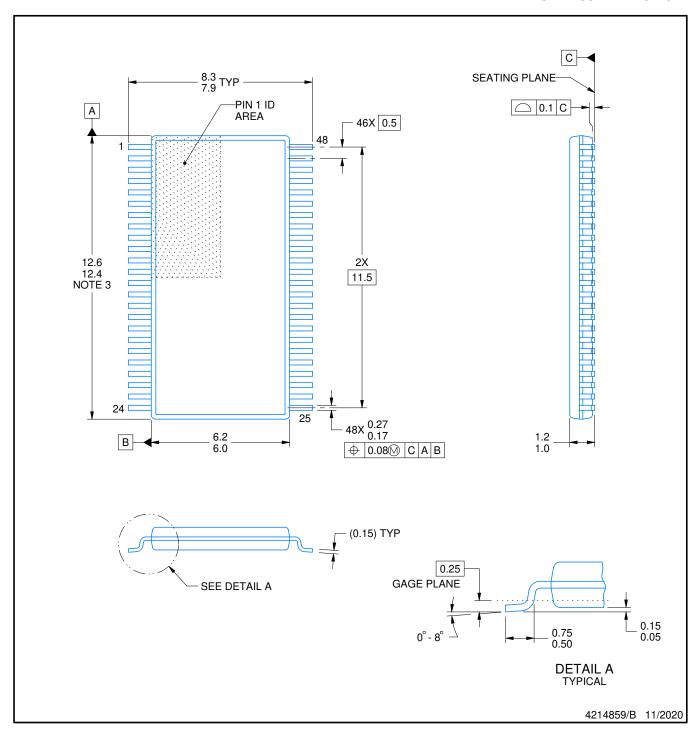


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74AHC16540DL	DL	SSOP	48	25	473.7	14.24	5110	7.87



SMALL OUTLINE PACKAGE



NOTES:

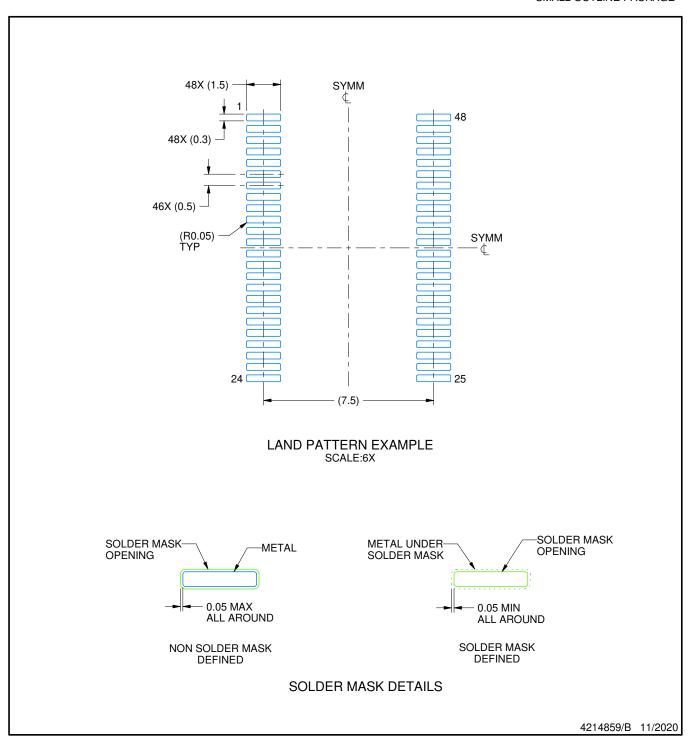
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE

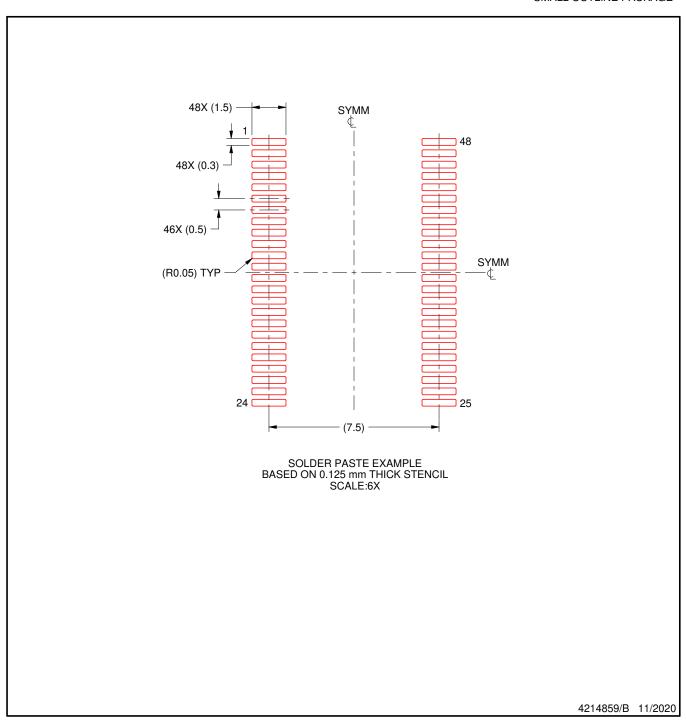


NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

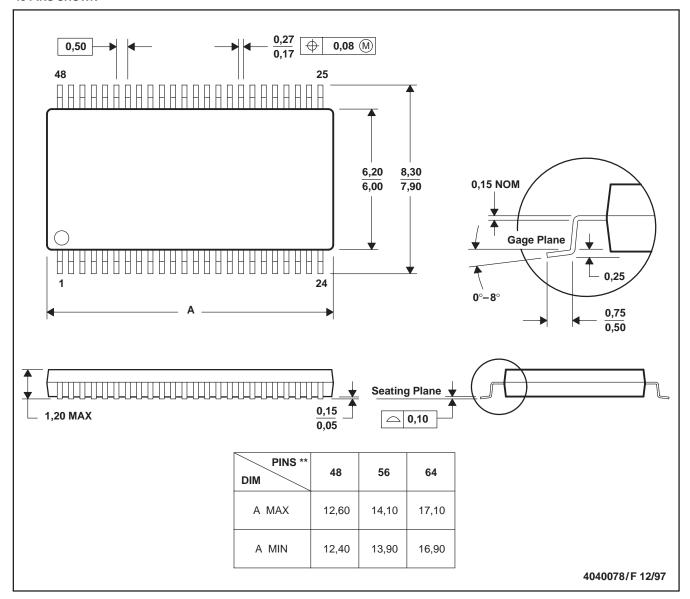
- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

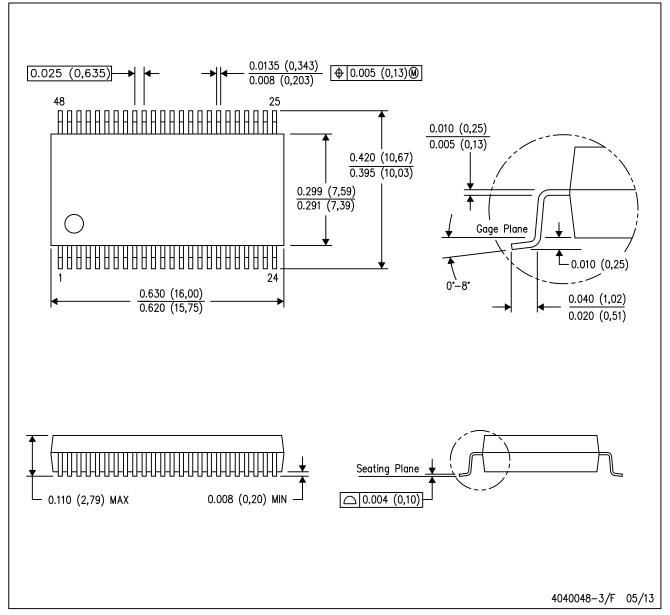
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

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